

# Dependence of the selectivity of SnO<sub>2</sub> nanorod gas sensors on functionalization materials

Sunghoon Park · Soohyun Kim · Hyunsung Ko · Chongmu Lee

Received: 4 March 2014 / Accepted: 12 May 2014 / Published online: 31 May 2014  
© Springer-Verlag Berlin Heidelberg 2014

**Abstract** Effects of functionalization materials on the selectivity of SnO<sub>2</sub> nanorod gas sensors were examined by comparing the responses of SnO<sub>2</sub> one-dimensional nanostructures functionalized with CuO and Pd to ethanol and H<sub>2</sub>S gases. The response of pristine SnO<sub>2</sub> nanorods to 500 ppm ethanol was similar to 100 ppm H<sub>2</sub>S. CuO-functionalized SnO<sub>2</sub> nanorods showed a slightly stronger response to 100 ppm H<sub>2</sub>S than to 500 ppm ethanol. In contrast, Pd-functionalized SnO<sub>2</sub> nanorods showed a considerably stronger response to 500 ppm ethanol than to 100 ppm H<sub>2</sub>S. In other words, the H<sub>2</sub>S selectivity of SnO<sub>2</sub> nanorods over ethanol is enhanced by functionalization with CuO, whereas the ethanol selectivity of SnO<sub>2</sub> nanorods over H<sub>2</sub>S is enhanced by functionalization with Pd. This result shows that the selectivity of SnO<sub>2</sub> nanorods depends strongly on the functionalization material. The ethanol and H<sub>2</sub>S gas sensing mechanisms of CuO- and Pd-functionalized SnO<sub>2</sub> nanorods are also discussed.

## 1 Introduction

A range of CuO–SnO<sub>2</sub> composite nanostructures based on SnO<sub>2</sub> and CuO have been reported for H<sub>2</sub>S sensing since the pioneering work of Moekawa et al. [1] on CuO-doped SnO<sub>2</sub> thick films. These nanostructures include CuO–SnO<sub>2</sub>

heterostructures [2–4], CuO-doped SnO<sub>2</sub> nanorods [5] and CuO-doped SnO<sub>2</sub> nanoribbons [6, 7]. The extraordinarily enhanced H<sub>2</sub>S sensing properties of CuO-doped SnO<sub>2</sub> nanorods are usually explained by the formation of a resistive heterojunction between p-type CuO and n-type SnO<sub>2</sub> in an air atmosphere, the reaction of the semiconducting CuO with H<sub>2</sub>S to form metallic CuS with a high conductivity upon exposure to H<sub>2</sub>S, and the strong chemical affinity of the alkaline CuO toward the acidic H<sub>2</sub>S gas [1, 7–9].

The response of SnO<sub>2</sub> nanorods to NO<sub>2</sub> were reported to be degraded by functionalization with CuO [10], suggesting their selective sensing performance to H<sub>2</sub>S. The selectivity of CuO-functionalized SnO<sub>2</sub> nanorods toward H<sub>2</sub>S must be attributed to the above three mechanisms, but it might be related more intimately to the second one of the three mechanisms. This assumption is supported by the excellent sensing properties of Pd-functionalized CuO nanorods toward H<sub>2</sub>S gas [11]. Nevertheless, the dependence of the selectivity of the SnO<sub>2</sub> nanorod-based gas sensors on the functionalization or doping material has not been clarified until now, even if there are many reports on the extraordinary H<sub>2</sub>S sensing properties of CuO-functionalized SnO<sub>2</sub> nanorods. To elucidate the dependence of the selectivity on the functionalization or doping material, this study examined the effects of functionalization materials on the selectivity of SnO<sub>2</sub> nanorod gas sensors by comparing the responses of SnO<sub>2</sub> one-dimensional (1D) nanostructures functionalized with CuO and Pd to ethanol (C<sub>2</sub>H<sub>5</sub>OH) and H<sub>2</sub>S gases. In addition, this study examined whether functionalization of SnO<sub>2</sub> nanostructures with CuO has adverse effects on the sensing properties of other gases than H<sub>2</sub>S by examining the response of CuO-functionalized SnO<sub>2</sub> nanorods to ethanol gas.

S. Park · S. Kim · H. Ko · C. Lee (✉)  
Department of Materials Science and Engineering, Inha University, 253 Yonghyun-dong, Nam-gu, Incheon 402-751, Republic of Korea  
e-mail: cmlee@inha.ac.kr

## 2 Experimental

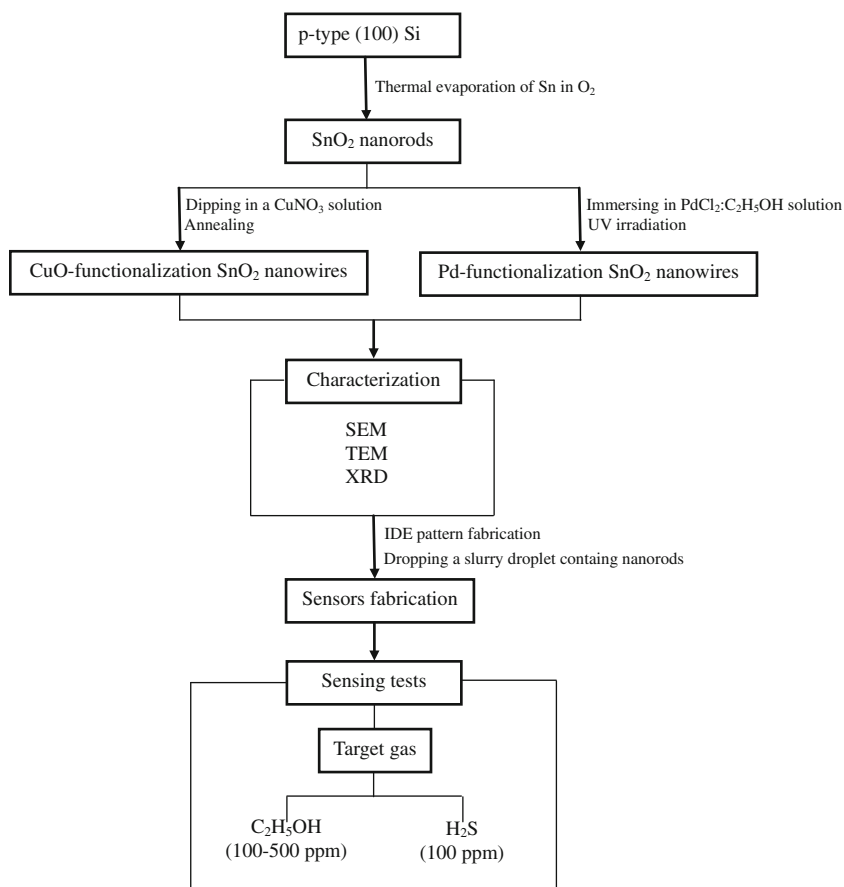
Figure 1 displays the process flow of sample preparation and sensing tests carried out in this study. CuO-functionalized SnO<sub>2</sub> nanorods were synthesized using a three-step process: the thermal evaporation of Sn powders in an oxidizing atmosphere, dipping in a CuNO<sub>3</sub> solution and thermal annealing. First, Au-coated Si was used as a substrate for the synthesis of 1D SnO<sub>2</sub> structures. A 3-nm-thick Au thin film was deposited on p-type (100) Si substrates by direct current (dc) magnetron sputtering. A quartz tube was mounted horizontally inside a tube furnace. A total of 99.99 % pure Sn powders were placed on the lower holder at the center of the quartz tube. The Au-coated Si substrate was placed on the upper holder, approximately 5 mm away from the Sn powders. The furnace was heated to 900 °C and maintained at that temperature for 1 h in a N<sub>2</sub>/3 mol%-O<sub>2</sub> atmosphere with constant flow rates of O<sub>2</sub> (10 sccm) and N<sub>2</sub> (300 sccm). The total pressure was set to 1.0 Torr. Subsequently, the as-synthesized SnO<sub>2</sub> nanorods were dipped into a 1 M Cu(NO<sub>3</sub>)<sub>2</sub> solution for 1 h and then cleaned with distilled water. The CuO-coated SnO<sub>2</sub> nanorods were annealed at

500 °C for 1 h in an oxygen atmosphere for 1 h (O<sub>2</sub> gas flow rate: 500 sccm).

The Pd-functionalized SnO<sub>2</sub> nanorods were also prepared by coating the as-synthesized SnO<sub>2</sub> nanorods with Pd using a wet chemistry method. An ethanolic palladium chloride solution (C<sub>2</sub>H<sub>5</sub>OH: PdCl<sub>2</sub> = 1,000:1) was prepared in a vial. The nanorod samples were immersed in that solution, and the vial was placed in a homemade ultraviolet (UV) box. The solution in a vial was then irradiated with 254 nm UV light at 3 mW/cm<sup>2</sup> for 20 min. Finally, the samples were annealed at 480 °C for 1 h in an Ar atmosphere. The Ar gas flow rate and process pressure were 100 cm<sup>3</sup>/min and 1.0 Torr, respectively.

The morphology and structure of the products were characterized by scanning electron microscopy (SEM, Hitachi S-4200) operating at 10 kV and transmission electron microscopy (TEM, JEOL 2100F) with an accelerating voltage of 300 kV. The crystal structure of the nanorods was examined by glancing angle X-ray diffraction (XRD, Philips X'pert MRD diffractometer) using Cu K<sub>α</sub> radiation ( $\lambda = 0.15406$  nm) at a scan rate of 4°/min. The sample was arranged geometrically at a 0.5° glancing angle with a rotating detector.

**Fig. 1** Process flow of sample preparation and sensing tests



For the sensing measurements, Ni ( $\sim 200$  nm in thickness) and Au ( $\sim 50$  nm) thin films were deposited sequentially by sputtering to form electrodes using an interdigital electrode mask. Three different types of nanorod samples: pristine SnO<sub>2</sub> nanorods, CuO-functionalized SnO<sub>2</sub> nanorods and Pd-functionalized SnO<sub>2</sub> nanorods were dispersed ultrasonically in a mixture of deionized water (5 ml) and isopropyl alcohol (5 ml) and dried at 90 °C for 30 min. A 200-nm-thick SiO<sub>2</sub> film was grown thermally on single crystalline Si (100) substrates. A slurry droplet containing the nanorods (10  $\mu$ l) was dropped onto the SiO<sub>2</sub>-coated Si substrates equipped with a pair of interdigitated (IDE) Ni ( $\sim 200$  nm)/Au ( $\sim 50$  nm) electrodes with a gap of 20  $\mu$ m. The gas sensing properties of the three different multiple networked nanorod sensors made from the three different types of nanorods were measured at 300 °C in a quartz tube placed in a sealed chamber with an electrical feed through. During the measurements, the sensors were placed in a sealed quartz tube with an electrical feed through. A set amount of C<sub>2</sub>H<sub>5</sub>OH (>99.99 %) or H<sub>2</sub>S gas was injected into the testing tube through a microsyringe to obtain a C<sub>2</sub>H<sub>5</sub>OH concentration of 100–500 ppm or a H<sub>2</sub>S concentrations of 100 ppm while the electrical current in the nanotubes was monitored. The response of the sensors is defined as  $R_a/R_g \times 100(\%)$  both for C<sub>2</sub>H<sub>5</sub>OH and H<sub>2</sub>S, where  $R_a$  and  $R_g$  are the electrical resistances in the sensors in air and the target gas, respectively.

### 3 Results and discussion

Figure 2a, b shows low-magnification and high-resolution TEM (HRTEM) images, respectively, of a typical CuO-functionalized SnO<sub>2</sub> nanorod. Figure 2c is selected area electron diffraction pattern corresponding to Fig. 2b. A comparison of Fig. 2a with the inset in Fig. 2a reveals that a CuO-functionalized SnO<sub>2</sub> nanorod (Fig. 2a) has many particles (dark globular particles) on the nanorod, whereas a pristine SnO<sub>2</sub> nanorod does not have such dark globular particles on it. HRTEM image (Fig. 2b) revealed fringes with spacings of 0.264 and 0.237 nm, corresponding to the interplanar distances of the {101} and {200} lattice planes, respectively, in bulk crystalline SnO<sub>2</sub>. Figure 2c shows dim diffractions spots assigned to monoclinic-structured CuO particles as well as intense diffraction spots assigned to tetragonal-structured SnO<sub>2</sub> nanorods, verifying the existence of CuO particles on the surface of SnO<sub>2</sub> nanorods. The XRD pattern of CuO-functionalized SnO<sub>2</sub> nanorods (Fig. 2d) showed both the reflection peaks assigned to tetragonal-structured SnO<sub>2</sub> with lattice constants of  $a = 0.4737$  nm and  $c = 0.3186$  nm (JCPDS No. 88-0287) and those assigned to monoclinic CuO with lattice

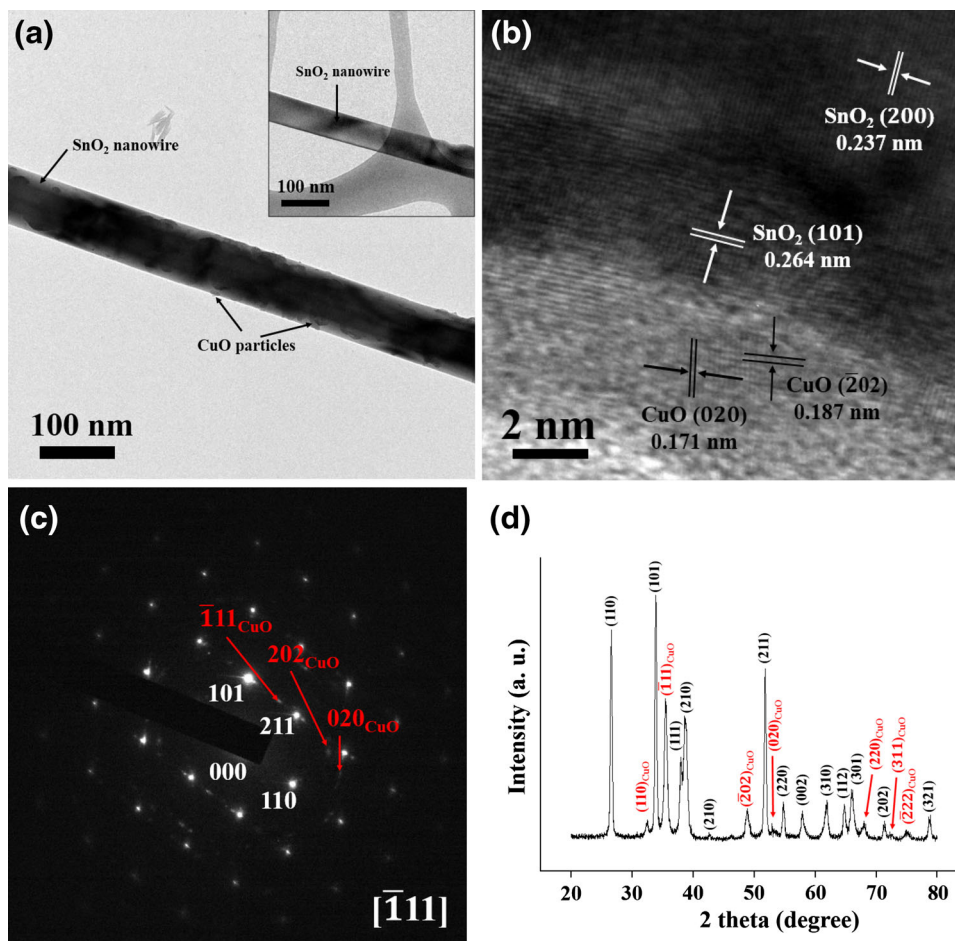
constants of  $a = 0.4689$  nm,  $b = 0.342$  nm,  $c = 0.513$  nm,  $\beta = 99.57^\circ$  (JCPDS No. 89-5899).

Figure 3a shows the low-magnification TEM image of a typical Pd-functionalized SnO<sub>2</sub> nanorod. Many small particles with diameters ranging from 3 to 20 nm are observable on the surface of the nanorod. An HRTEM image shows the two different regions with different fringe patterns clearly: (a) the upper part of the image shows a fringe pattern with a spacing of 0.225 corresponding to the interplanar distance of the {111} lattice plane in bulk crystalline Pd, whereas (b) the lower part shows two types of fringes with spacings of 0.264 and 0.237 nm, corresponding to the interplanar distances of the {101} and {200} lattice planes, respectively, in bulk crystalline SnO<sub>2</sub>, respectively. The corresponding diffraction pattern (Fig. 3c) displays dim spots as well as intense diffraction spots assigned to tetragonal-structured SnO<sub>2</sub>. A structural analysis of the dim spotty pattern identified the pattern to be of face-centered cubic Pd, whereas small peaks located at  $\sim 39^\circ$ ,  $\sim 47^\circ$  and  $\sim 69^\circ$  were assigned to the (111), (200) and (220) reflections, respectively, of face-centered cubic-structured Pd. The XRD pattern of Pd-functionalized SnO<sub>2</sub> nanorods (Fig. 3d) shows several small reflection peaks assigned to Pd as well as tall reflection peaks assigned to SnO<sub>2</sub>. The relatively weak reflection intensities of Pd compared to those of SnO<sub>2</sub> might be due to the far smaller amount of Pd compared to that of SnO<sub>2</sub> in the nanorods.

Figure 4a–c shows the dynamic responses of the pristine, CuO-functionalized SnO<sub>2</sub> nanorods and Pd-functionalized SnO<sub>2</sub> nanorods to a reducing gas C<sub>2</sub>H<sub>5</sub>OH at 300 °C, respectively. The sensor responded well to ethanol gas. The resistance decreased rapidly when the nanorod sensors were exposed to ethanol gas and recovered almost to the initial value when the ethanol gas supply was stopped and air was introduced. The responses of the CuO-functionalized SnO<sub>2</sub> nanorods were quite stable and reproducible for repeated testing. Table 1 lists the responses calculated from Fig. 4a–c. The pristine SnO<sub>2</sub> nanorods showed responses of approximately 137, 151, 165, 181 and 211 % to 100, 200, 300, 400 and 500 ppm C<sub>2</sub>H<sub>5</sub>OH, respectively. In contrast, the CuO-functionalized SnO<sub>2</sub> nanorods and Pd-functionalized SnO<sub>2</sub> nanorods showed corresponding responses of approximately 170, 192, 240, 320 and 696 % and 173, 195, 250, 365 and 590 %, respectively, to 100, 200, 300, 400 and 500 ppm C<sub>2</sub>H<sub>5</sub>OH. Consequently, functionalizing SnO<sub>2</sub> nanorods with CuO and Pd led to 1.2–3.3- and 1.3–2.8-fold stronger responses, respectively, to 100–500 ppm ethanol gases.

Figure 4d shows the responses determined from Fig. 4a–c as a function of the C<sub>2</sub>H<sub>5</sub>OH concentration. A linear relationship was observed between the response and the ethanol concentration in the ethanol gas concentration

**Fig. 2** **a** Low-magnification TEM image of a typical CuO-functionalized SnO<sub>2</sub> nanorod. **b** High-resolution TEM image and **c** corresponding SAED pattern of the CuO-SnO<sub>2</sub> interface region of a typical CuO-functionalized SnO<sub>2</sub> nanorod. **d** XRD patterns of the CuO-functionalized SnO<sub>2</sub> nanorods



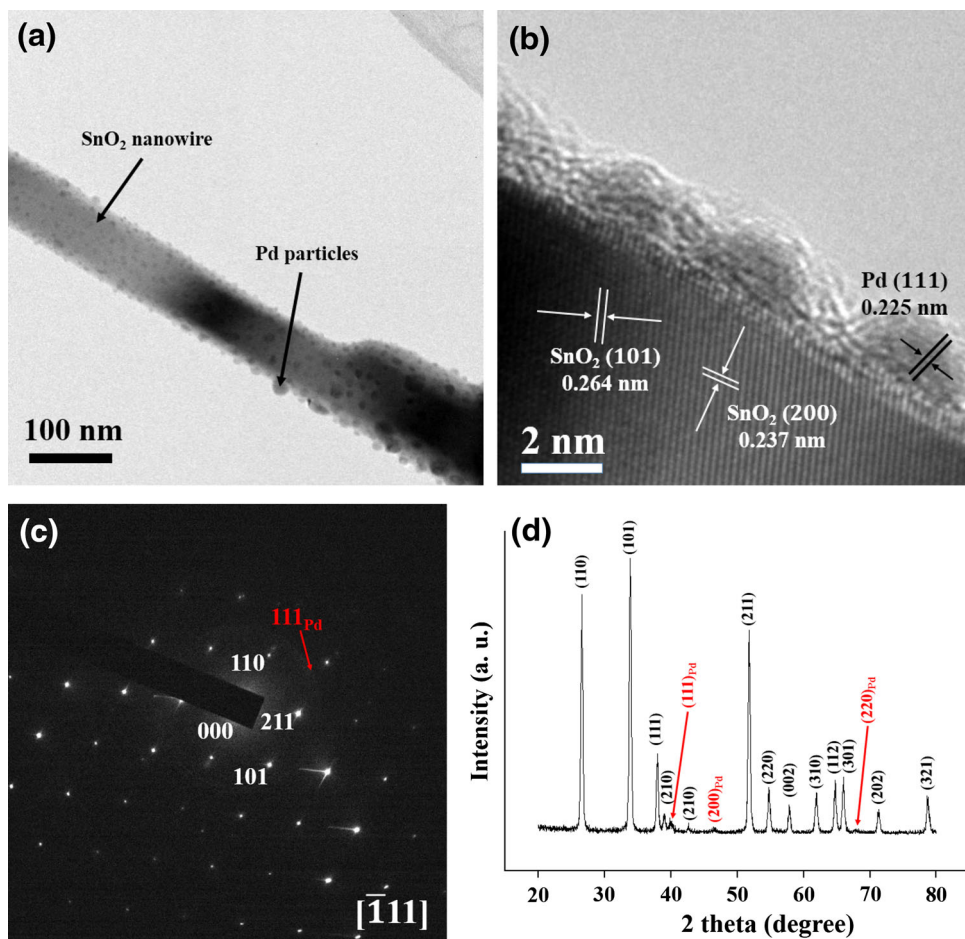
range of 100–500 ppm. The response of an oxide semiconductor can normally be expressed as  $R = A [C]^n + B$ , where  $A$  and  $B$ ,  $n$ , and  $[C]$  are constants, exponent, and target gas concentration, respectively [12]. Data fitting gave  $R = 1.18 [C] - 29.9$ ,  $R = 1.00 [C] + 13.5$  and  $R = 0.179 [C] + 115.2$  for the CuO-functionalized SnO<sub>2</sub> nanorods, Pd-functionalized SnO<sub>2</sub> nanorods and pristine SnO<sub>2</sub> nanorods, respectively. The responses of these three different SnO<sub>2</sub> nanorod sensors tended to increase with increasing C<sub>2</sub>H<sub>5</sub>OH gas concentration, but the responses of the CuO- or Pd-functionalized SnO<sub>2</sub> nanorods tended to increase more rapidly than that of the pristine SnO<sub>2</sub> nanorods. In particular, the response of the CuO-functionalized SnO<sub>2</sub> nanorods was higher than Pd-functionalized SnO<sub>2</sub> nanorods at high C<sub>2</sub>H<sub>5</sub>OH concentrations, whereas the former was lower than the latter at low C<sub>2</sub>H<sub>5</sub>OH concentrations.

Another thing to note is the jump in response between 400 and 500 ppm C<sub>2</sub>H<sub>5</sub>OH. It is not well understood at present why the sensing response to 500 ppm ethanol was significantly increased compared to the ones of 400 ppm ethanol for the functionalized SnO<sub>2</sub> nanorods. In general, the sensitivity or response can jump at a critical temperature

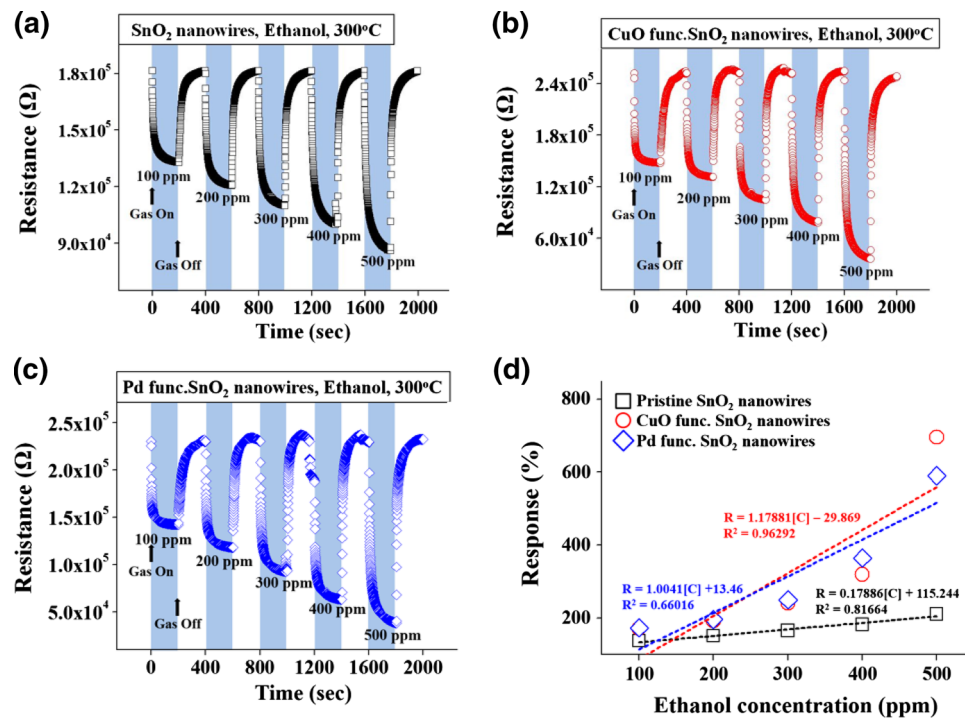
as the temperature increases because of change in sensing mechanism. On the other hand, it is seldom that the sensitivity or response jumps at a critical gas concentration as the concentration increase because of no change in sensing mechanism. A further systematic study may be necessary to reveal the cause of the significant increase. The significant increase in response in this study is probably due to the experimental error rather than due to change in sensing mechanism. The important concentration range in detecting gas depends on the kind of gas. For example, in the case of ethanol sensing, the gas concentrations studied commonly range from 100 to 10,000 ppm. Most previous studies reported that the sensing response increased quite a bit in the ethanol concentration range from 400 to 500 ppm with increasing the ethanol concentration. Therefore, the result in this study that the significant increase in the sensing response to 500 ppm ethanol was significantly increased compared to the ones of 400 ppm ethanol is not much surprising. We imagine further increases in ethanol concentration to 10,000 ppm might lead to the saturation of the ethanol sensing properties.

Figure 5 compares the responses of the pristine, CuO-functionalized and Pd-functionalized SnO<sub>2</sub> nanorods to

**Fig. 3** **a** Low-magnification TEM image of a typical Pd-functionalized SnO<sub>2</sub> nanorod. **b** High-magnification TEM image and **c** corresponding SAED pattern of the Pd-SnO<sub>2</sub> interface region of a typical Pd-functionalized SnO<sub>2</sub> nanorod. **d** XRD pattern of Pd-functionalized SnO<sub>2</sub> nanorods

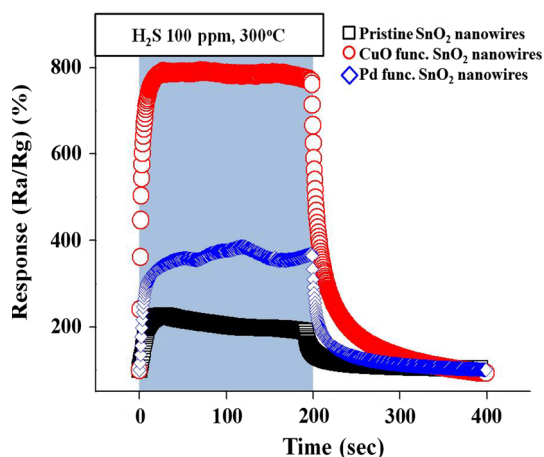


**Fig. 4** Electrical responses of the gas sensors fabricated from **a** pristine, **b** CuO-functionalized SnO<sub>2</sub> nanorods and **c** Pd-functionalized SnO<sub>2</sub> nanorods to 100, 200, 300, 400 and 500 ppm ethanol gas at 300 °C. **d** Responses of pristine, CuO-functionalized and Pd-functionalized SnO<sub>2</sub> nanorods as a function of ethanol concentration



**Table 1** Responses of the pristine, CuO-functionalized and Pd-functionalized SnO<sub>2</sub> nanorods to ethanol gas

Ethanol conc. (ppm)	Response (%)		
	SnO <sub>2</sub>	CuO-functionalized SnO <sub>2</sub>	Pd-functionalized SnO <sub>2</sub>
100	136.67	170.64	172.64
200	150.62	191.97	195.84
300	165.07	240.40	249.87
400	181.48	319.66	364.94
500	210.67	696.20	590.15

**Fig. 5** Comparison of the responses of pristine, CuO-functionalized and Pd-functionalized SnO<sub>2</sub> nanorods to H<sub>2</sub>S gas**Table 2** Responses of pristine, CuO-functionalized and Pd-functionalized SnO<sub>2</sub> nanorods to 100 ppm H<sub>2</sub>S gas and 500 ppm ethanol

Nanomaterials	Response to 100 ppm H <sub>2</sub> S gas (%)	Response to 500 ppm C <sub>2</sub> H <sub>5</sub> OH (%)
Pristine SnO <sub>2</sub> nanorods	207.66	210.67
CuO-functionalized SnO <sub>2</sub> nanorods	798.12	696.20
Pd-functionalized SnO <sub>2</sub> nanorods	387.54	590.15

H<sub>2</sub>S gas. As reported previously, CuO-functionalized SnO<sub>2</sub> nanorods showed considerably stronger responses than those of the Pd-functionalized and pristine SnO<sub>2</sub> nanorods, suggesting that the CuO-functionalized SnO<sub>2</sub> nanorods are an excellent H<sub>2</sub>S gas sensor. Table 2 showed the difference in selectivity between the CuO- and Pd-functionalized SnO<sub>2</sub> nanorods. The selectivity of the two nanomaterials can be compared reasonably from the responses

summarized in Table 2 because the pristine SnO<sub>2</sub> nanorods showed similar response to 100 ppm H<sub>2</sub>S to that to 500 ppm C<sub>2</sub>H<sub>5</sub>OH. CuO-functionalized SnO<sub>2</sub> showed a stronger response to 500 ppm ethanol than to 100 ppm H<sub>2</sub>S, but the difference was small. In contrast, the Pd-functionalized SnO<sub>2</sub> nanorods showed a considerably stronger response to 100 ppm H<sub>2</sub>S than that to 500 ppm C<sub>2</sub>H<sub>5</sub>OH. Therefore, the ethanol selectivity of the SnO<sub>2</sub> nanorods over H<sub>2</sub>S is enhanced by functionalization with Pd, whereas the H<sub>2</sub>S selectivity of SnO<sub>2</sub> nanorods over C<sub>2</sub>H<sub>5</sub>OH is enhanced by functionalization with CuO.

Figure 6a–c shows the dependence of the responses of CuO-functionalized and Pd-functionalized SnO<sub>2</sub> nanorods to ethanol gas. Both the CuO-functionalized (Fig. 6a) and Pd-functionalized (Fig. 6b) SnO<sub>2</sub> nanorods show that their responses to 500 ppm ethanol increased with increasing temperature up to 300 °C and then decreased with a further increase in temperature from 300 to 350 °C. The response of CuO-functionalized SnO<sub>2</sub> nanorods was higher than that of Pd-functionalized SnO<sub>2</sub> nanorods at any temperature in the temperature range of 200–350 °C (Fig. 6c). These results suggest that the relative selectivities of the SnO<sub>2</sub> nanorods functionalized with two different materials do not change with temperature in this temperature range. In other words, the relative sensitivities and selectivities of the SnO<sub>2</sub> nanorods are independent of the temperature and functionalization material.

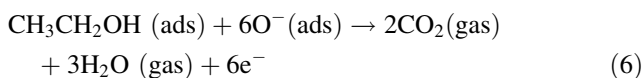
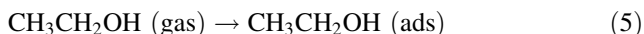
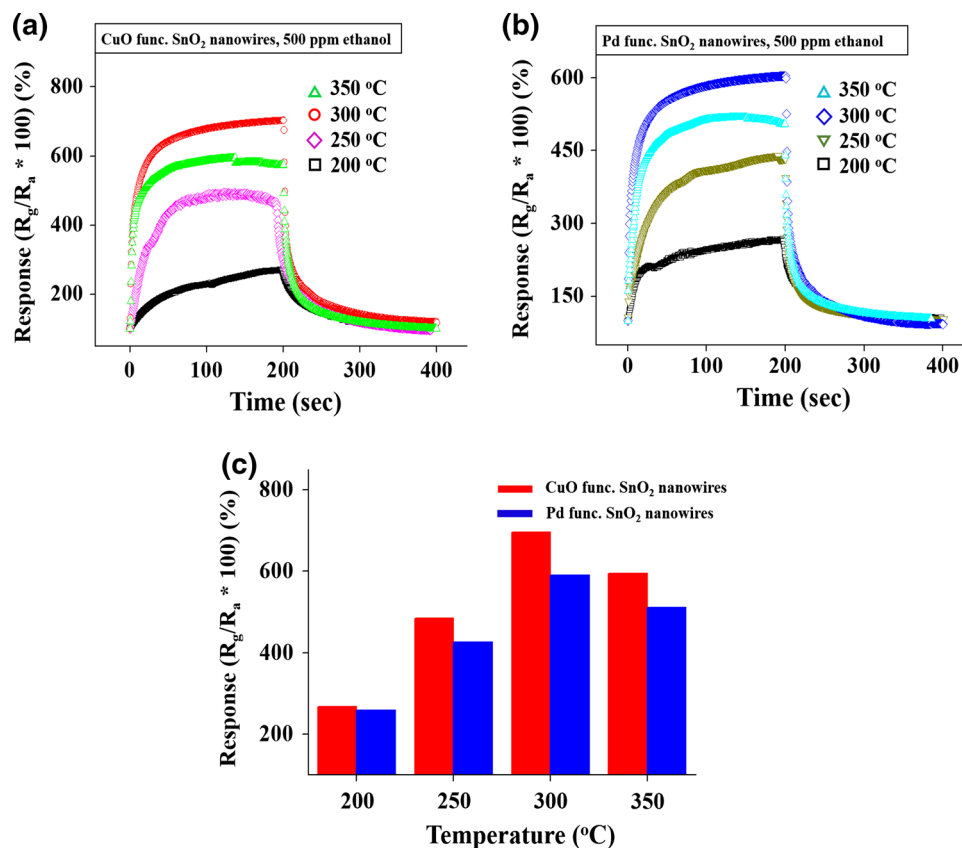
The ethanol gas sensing mechanism of the SnO<sub>2</sub> nanorod sensor can be modeled using the surface-depletion model [13]. When the SnO<sub>2</sub> nanorod sensor is exposed to air, it interacts with oxygen by transferring electrons from the conduction band to the adsorbed oxygen atoms, forming ionic species, such as O<sup>-</sup>, O<sup>2-</sup> and O<sub>2</sub><sup>-</sup>, as illustrated below.



A depletion region is created in the wall of the SnO<sub>2</sub> nanorods due to the consumption of electrons in the surface region of the SnO<sub>2</sub> nanorods [14], resulting in an increase in the electrical resistance of the SnO<sub>2</sub> nanorods. The surface depletion layer thickness, the potential barrier and the electrical resistance increase with increasing the number of oxygen ions on the surface [15].

When the sensor is exposed to ethanol gas, C<sub>2</sub>H<sub>5</sub>OH molecules will react with the preexisting oxygen ions on the SnO<sub>2</sub> nanorod surface to form CO<sub>2</sub> and H<sub>2</sub>O according to the following equation and the electrons are released back to the SnO<sub>2</sub> nanorods [16]:

**Fig. 6** Responses of **a** CuO-functionalized and **b** Pd-functionalized SnO<sub>2</sub> nanorods to 500 ppm ethanol gas for different temperatures. **c** Comparison of the responses of CuO-functionalized and Pd-functionalized SnO<sub>2</sub> nanorods to 500 ppm ethanol gas at different temperatures in the temperature range of 200–350 °C



This leads to an increase in carrier concentration in the SnO<sub>2</sub> nanorod surface and a decrease in the surface depletion layer width. In other words, the depleted electrons are returned to the conduction band, which results in a sharp decrease in the electrical resistance of the SnO<sub>2</sub> nanorod sensors.

The enhanced response of the CuO-functionalized SnO<sub>2</sub> nanorods to ethanol gas might be due to the formation of a p-CuO–n-SnO<sub>2</sub> junction. The modulation of electron transport by this pn-junction with an adjustable energy barrier height would result in response to C<sub>2</sub>H<sub>5</sub>OH as high as that of the Pd-functionalized SnO<sub>2</sub> nanorods. In contrast, the main underlying sensing mechanism of the p-CuO (nanoparticle)/n-SnO<sub>2</sub> (nanorod) heterostructures upon exposure to H<sub>2</sub>S was described in the literature [17]. The chemically specific transformation from p-CuO to metallic CuS modifies the depleted region formed at the p-CuO/n-SnO<sub>2</sub> interface and restricts the conduction channel inside the nanorods in an oxygen-rich atmosphere. Upon exposure to H<sub>2</sub>S, copper oxide undergoes a sulphurization process to

form CuS with metallic characteristics according to the following reaction [18–21]:



Under these conditions, highly resistive p-CuO transforms to conducting Cu<sub>2</sub>S, changing the heterostructure from a standard pn-junction to a metal–semiconductor junction. The breakup of the pn-junction and the formation of a metal–semiconductor junction increase the conduction section in the nanorod, leading to a significant improvement in conductivity. Second-order effects such as the oxidation of CuS by oxygen adsorbed on the CuO nanoparticles might also contribute to p–n junction modulation. These two phenomena lead to much stronger response to H<sub>2</sub>S gas than that caused by standard redox surface reactions in metal oxides [22].

On the other hand, the enhanced responses of the Pd-functionalized SnO<sub>2</sub> nanorods to C<sub>2</sub>H<sub>5</sub>OH and H<sub>2</sub>S gases can be explained by the combination of a catalytic mechanism based on the spillover effect and an electronic mechanism [23]. In particular, the selectivity of the Pd-functionalized SnO<sub>2</sub> nanorods to C<sub>2</sub>H<sub>5</sub>OH over H<sub>2</sub>S gases can be explained by the catalytic activity of C<sub>2</sub>H<sub>5</sub>OH

oxidation boosted by Pd. Many oxide semiconductors including SnO<sub>2</sub> commonly show selective detection to C<sub>2</sub>H<sub>5</sub>OH. This high C<sub>2</sub>H<sub>5</sub>OH selectivity was reported to be due to the high oxygen concentration and high catalytic oxidation activity of C<sub>2</sub>H<sub>5</sub>OH [23]. Actually, the adsorbed C<sub>2</sub>H<sub>5</sub>OH molecules on the Pd surface would react with adsorbed oxygen species on the SnO<sub>2</sub> surface, and hence, the sensitivity of the metal oxide sensor should depend upon the catalytic activity for C<sub>2</sub>H<sub>5</sub>OH oxidation. Therefore, the high C<sub>2</sub>H<sub>5</sub>OH selectivity of the Pd-functionalized SnO<sub>2</sub> nanorod sensor at 300 °C over H<sub>2</sub>S might also be attributed to the higher oxygen concentration and the higher catalytic oxidation activity of C<sub>2</sub>H<sub>5</sub>OH on Pd surface than that of H<sub>2</sub>S. One thing worthy of noting regarding the gas sensing selectivity of the Pd-functionalized SnO<sub>2</sub> nanorods is that the roles of Pd in the gas sensing reaction, as reported in the literature, have not always been consistent [23]. This suggests that Pd plays a complicated role that varies according to its doping concentration [24, 25], sensor temperature [26], loading methods [24, 27], and the species of target gas [28–31].

#### 4 Summary

Multiple networked CuO- and Pd-functionalized SnO<sub>2</sub> nanorod sensors showed significantly stronger electrical responses to C<sub>2</sub>H<sub>5</sub>OH and H<sub>2</sub>S gases at 300 °C compared to their pristine SnO<sub>2</sub> nanorod counterparts. The pristine SnO<sub>2</sub> nanorod sensors exhibited a response of 211 % to 500 ppm C<sub>2</sub>H<sub>5</sub>OH at 300 °C, whereas the CuO- and Pd-functionalized SnO<sub>2</sub> nanorod sensors showed a response of 696 and 590 %, respectively, under the same conditions. On the other hand, the pristine SnO<sub>2</sub> nanorod sensors exhibited a response of 208 % to 100 ppm C<sub>2</sub>H<sub>5</sub>OH at 300 °C, whereas the CuO- and Pd-functionalized SnO<sub>2</sub> nanorod sensors showed a response of 798 % and 388 %, respectively, under the same conditions. The C<sub>2</sub>H<sub>5</sub>OH selectivity of the SnO<sub>2</sub> nanorods over H<sub>2</sub>S was enhanced by functionalization with Pd, whereas the H<sub>2</sub>S selectivity of the SnO<sub>2</sub> nanorods over C<sub>2</sub>H<sub>5</sub>OH was enhanced by functionalization with CuO. The enhanced responses of the CuO-functionalized SnO<sub>2</sub> nanorods to ethanol and H<sub>2</sub>S gases can be attributed to the formation of a p-CuO–n-SnO<sub>2</sub> junction and a metal–semiconductor junction, respectively. Both the CuO- and Pd-functionalized SnO<sub>2</sub> nanorods showed that their responses to 500 ppm ethanol increased with increasing temperature up to 300 °C and then decreased with a further increase in temperature from 300 to 350 °C. On the other hand, the relative selectivities of the SnO<sub>2</sub> nanorods functionalized with two different materials do not change with temperature in the temperature range of 200–350 °C. The enhanced responses of the

Pd-functionalized SnO<sub>2</sub> nanorods to C<sub>2</sub>H<sub>5</sub>OH and H<sub>2</sub>S gases can be explained by the combination of a catalytic mechanism based on the spillover effect and an electronic mechanism. In particular, the selectivity of the Pd-functionalized SnO<sub>2</sub> nanorods to C<sub>2</sub>H<sub>5</sub>OH over H<sub>2</sub>S gases can be explained by the catalytic activity of C<sub>2</sub>H<sub>5</sub>OH oxidation boosted by Pd.

**Acknowledgments** This research was supported by Basic Science Research Program through the National Research Foundation of Korea (NRF) funded by the Ministry of Education (2010-0020163).

#### References

1. J. Tamaki, T. Maekawa, N. Miura, N. Yamazoe, *Sens. Actuators B* **9**, 197–203 (1992)
2. J.H. Yoon, J.S. Kim, *Met. Mater. Int.* **00**, 773–777 (2010)
3. L. He, Y. Jia, F. Meng, M. Li, J. Liu, *J. Mater. Sci.* **44**, 4326–4333 (2009)
4. A. Khanna, R. Kumar, S.S. Bhatti, *Appl. Phys. Lett.* **82**, 4388–4390 (2003)
5. X. Xue, L. Xing, Y. Chen, S. Shi, Y. Wang, T. Wang, *J. Phys. Chem.* **C112**, 12157–12160 (2008)
6. F.N. Meng, X.P. Di, H.W. Dong, Y. Zhang, *Sens. Actuators B* **182**, 197–204 (2013)
7. A. Chowdhri, P. Sharma, V. Gupta, K. Sreenivas, K.V. Rao, *J. Appl. Phys.* **92**, 2172–2179 (2002)
8. G. Sarala, S. Manorama, V.J. Rao, High sensitivity and selectivity of an SnO<sub>2</sub> sensor to H<sub>2</sub>S at around 100 °C. *Sens. Actuators B* **28**, 31–37 (1995)
9. I.S. Hwang, J.K. Choi, S.J. Kim, K.Y. Dong, J.H. Kwon, B.K. Ju, J.H. Lee, Enhanced H<sub>2</sub>S sensing characteristics of SnO<sub>2</sub> nanowires functionalized with CuO. *Sens. Actuators B* **142**, 105–110 (2009)
10. S. Kim, H. Na, S. Choi, D. Kwak, H. Kim, Novel growth of CuO-functionalized, branched SnO<sub>2</sub> nanowires and their application to H<sub>2</sub>S sensors. *J. Phys. D Appl. Phys.* **45**, 205301–205308 (2012)
11. H. Kim, C. Jin, S. Park, S. Kim, C. Lee, H<sub>2</sub>S gas sensing properties of bare and Pd-functionalized CuO nanorods. *Sens. Actuators B* **161**, 594–599 (2012)
12. D.E. Williams, *Solid State Gas Sensors* (Hilger, Bristol, 1987)
13. O. Safonova, G. Delabouglise, B. Chenevier, A. Gaskov, M. Labeau, CO and NO<sub>2</sub> gas sensitivity of nanocrystalline tin dioxide thin films doped with Pd, Ru and Rh. *Mater. Sci. Eng. C* **21**, 105–111 (2002)
14. A. Kolmakov, M. Moskovits, Chemical sensing and catalysis by one-dimensional metal-oxide nanostructures. *Annu. Rev. Mater. Res.* **34**, 151–180 (2004)
15. S. Morrison, Selectivity in semiconductor gas sensors. *Sens. Actuators B* **12**, 425–440 (1987)
16. J. Li, H. Fan, X. Jia, W. Yang, P. Fang, Enhanced blue-green emission and ethanol sensing of Co-doped ZnO nanocrystals prepared by a solvothermal route. *Appl. Phys. A* **98**, 537–542 (2010)
17. J. Tamaki, K. Shimano, Y. Yamada, Y. Yamamoto, N. Miura, N. Yamazoe, Dilute hydrogen sulfide sensing properties of CuO–SnO<sub>2</sub> thin film prepared by low-pressure evaporation method. *Sens. Actuators, B* **49**, 121–125 (1998)
18. T. Pagnier, M. Boulouva, A. Galerie, A. Gaskov, G. Lucazeau, Reactivity of SnO<sub>2</sub>–CuO nanocrystalline materials with H<sub>2</sub>S: a coupled electrical and Raman spectroscopic study. *Sens. Actuators B Chem.* **71**, 134–139 (2000)



19. J. Dunn, C. Muzenda, Thermal oxidation of covellite (CuS). *Thermochim. Acta* **369**, 117–123 (2001)
20. S. Wang, Q. Huang, X. Wen, X. Li, S. Yang, Thermal oxidation of Cu<sub>2</sub>S nanowires: a template method for the fabrication of mesoscopic CuO ( $x = 1, 2$ ) wires. *Phys. Chem. Chem. Phys.* **4**, 3425–3429 (2002)
21. C. Mu, J. He, Confined conversion of CuS nanowires to CuO nanotubes by annealing-induced diffusion in nanochannels. *Nanoscale Res. Lett.* **6**, 150–155 (2011)
22. N. Barsan, U. Weimar, Conduction model of metal oxide gas sensors. *J. Electroceram.* **7**, 143–167 (2001)
23. J.K. Choi, I.S. Hwang, S.J. Kim, J.S. Park, S.S. Park, U. Jeong, Y.C. Kang, J.H. Lee, Design of selective gas sensors using electrospun Pd-doped SnO<sub>2</sub> hollow nanofibers. *Sens. Actuators B* **150**, 191–199 (2010)
24. S. Matsushima, T. Maekawa, J. Tamaki, N. Miura, N. Yamazoe, New methods for supporting palladium on a tin oxide gas sensor. *Sens. Actuators B* **9**, 71–78 (1992)
25. M. Yuasa, T. Masaki, T. Kida, K. Shimanoe, N. Yamazoe, Nano-sized PdO loaded SnO<sub>2</sub> nanoparticles by reverse micelle method for highly sensitive CO gas sensor. *Sens. Actuators B* **136**, 99–104 (2009)
26. L. Liu, T. Zhang, S. Li, L. Wang, T. Tian, Preparation, characterization, and gas-sensing properties of Pd-doped In<sub>2</sub>O<sub>3</sub> nanofibers. *Mater. Lett.* **63**, 1975–1977 (2009)
27. C.-B. Lim, S. Oh, Microstructure evolution and gas sensitivities of Pd-doped SnO<sub>2</sub>-based sensor prepared by three different catalyst-addition process. *Sens. Actuators B* **30**, 223–231 (1996)
28. N. Yamazoe, K. Kurokawa, T. Seiyama, Effects of additives on semiconductor gas sensor. *Sens. Actuators* **4**, 283–289 (1983)
29. G. Tournier, C. Pijolat, R. Lalauze, B. Patissier, Selective detection of CO and CH<sub>4</sub> with gas sensors using SnO<sub>2</sub> doped with palladium. *Sens. Actuators B* **26–27**, 24–28 (1995)
30. Y.C. Lee, H. Huang, O.K. Tan, M.S. Tse, Semiconductor gas sensor based on Pd doped SnO<sub>2</sub> nanorod thin films. *Sens. Actuators B* **132**, 239–242 (2008)
31. Y. Zhang, Q. Xiang, J. Xu, P. Xu, Q. Pan, F. Li, Self-assemblies of Pd nanoparticles on the surfaces of single crystal ZnO nanowires for chemical sensors with enhanced performances. *J. Mater. Chem.* **19**, 4701–4706 (2009)